

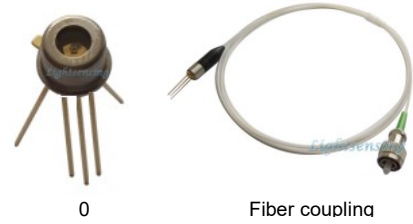
10G InGaAs M=30 Avalanche Photodiode

Version: sample 18-09-01

Model: LSIAPD-10G

Features:

- High reliability, low dark current
- 800-1700nm wavelength range
- High Gain up to M=30
- High rate up to 10Gbps
- Hermetic TO46 Can or with fiber coupling



Applications:

- Ultra Weak pulse optical detecting
- Optical fiber sensor, OTDR
- Laser lidar, laser range finding
- high resolution Optical Coherence Tomography
- Science analysis and experiment

The absolute values

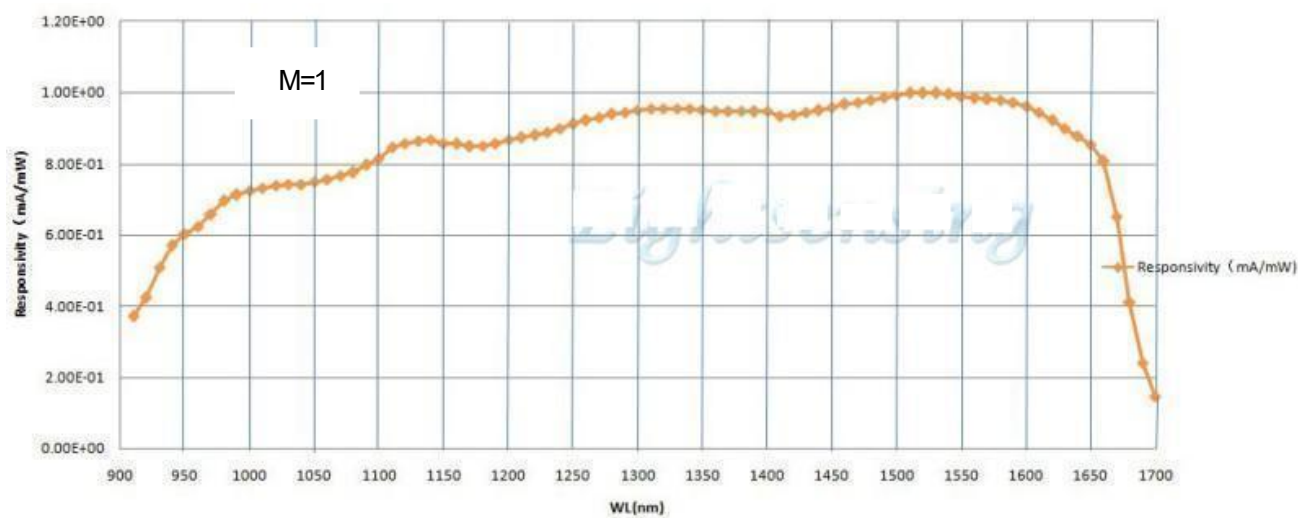
Operating voltage	$0.99 \times V_{BR}$	Operating temperature	$-40 \sim +85^{\circ}\text{C}$	Power dissipation	50mW
Forward current	4mA	storage temperature	$-45 \sim +100^{\circ}\text{C}$	Soldering temperature(time)	260°C (10s)

The opto-eletronic characteritics (@Tc=22±3℃)

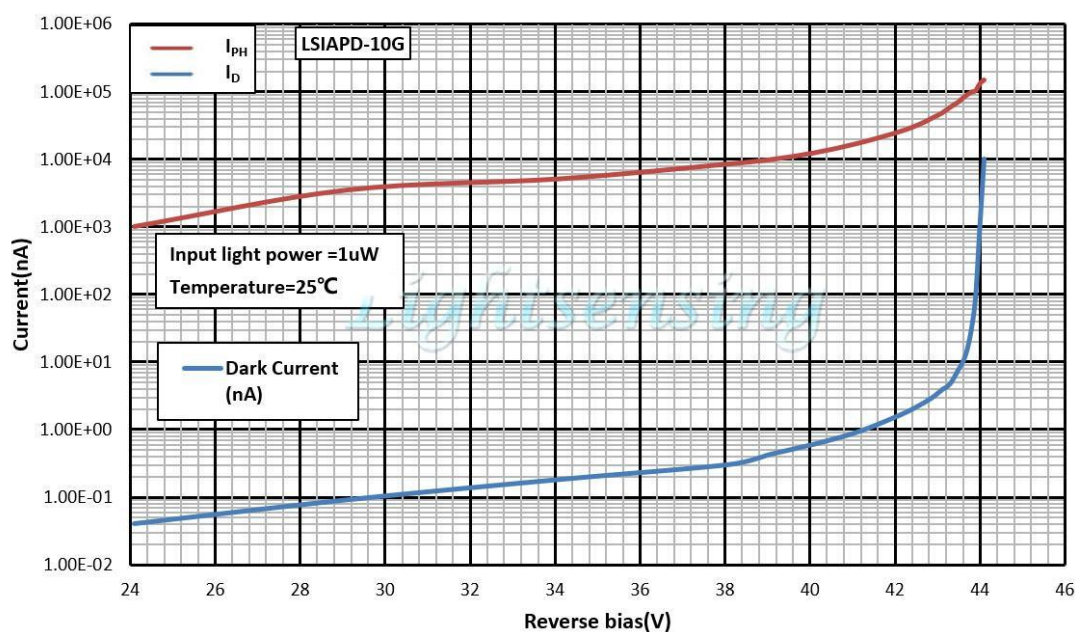
Parameters	Sym.	Test conditions	Min	Typ	Max	Unit
Response Spectrum	λ	—	800~1700			nm
Active diameter	φ	—	30			μm
Responsivity	Re	$\lambda=1.55\mu\text{m}, \varphi_e=1\mu\text{W}, M=1$		0.8		A/W
Multiplication gain	M	$\lambda=1.55\mu\text{m}, \varphi_e=1\mu\text{W}, V_{BR}=4\text{V}$		10		
		$\lambda=1.55\mu\text{m}, \varphi_e=1\mu\text{W}, V_{BR}=2\text{V}$		20		
		$\lambda=1.55\mu\text{m}, \varphi_e=1\mu\text{W}, V_{BR}=1.2\text{V}$		30		
Rate	R_B	$M=10, R_L=50\Omega$		10		Gbps
Dark current	I_D	$M=10$		0.5		nA
Total capacitance	C_{tot}	$M=10$		0.3		pF
Reverse breakdown voltage	V_{BR}	$I_R=10\mu\text{A}$	20	28	50	V
Maximum instantaneous input power	P	$M=10, 1550\text{nm}, 10\text{ns}, 10\text{KHZ}$			100	μW
Operating voltage temperature coefficient	δ	$T_c=-40 \sim +85^{\circ}\text{C}$		0.11	0.15	V/ $^{\circ}\text{C}$
package	Hermetic TO46 Can or with fiber coupling					

NOTICE: The above product specifications are subject to change without notice.

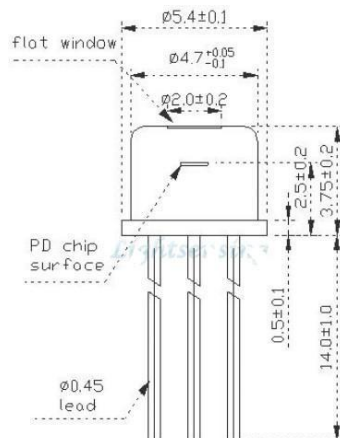
The typical characteristic curve



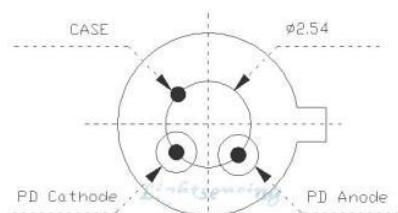
Dark current and photo current vs voltage



TO package and Lead



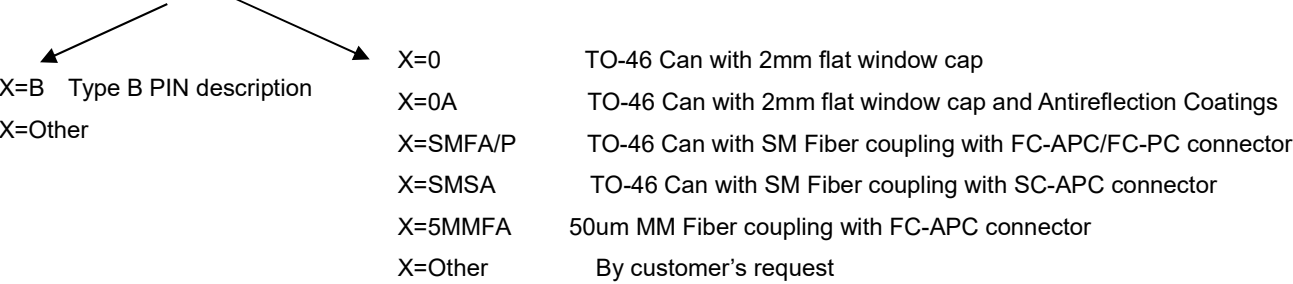
2mm flat window TO
Model: 0



Type B PIN description
Bottom View

Ordering information

LSIAPD-10G-X - X



The Cautions

- 1: The above product specifications are subject to change without notice.
- 2: The suitable ESD protecting measures are recommend in storage,transporting and using.
- 3: The fiber bending radius no less than 20mm for avoiding fiber damaged ,Be sure the fiber coupling facet is clean before connecting it to opto-circuit.